

Data sheet acquired from Harris Semiconductor SCHS068C – Revised October 2003

CD4503B Types

CMOS Hex Buffer

High-Voltage Types (20-Volt Rating) 3-State Non-Inverting Type

■ CD4503B is a hex noninverting buffer with 3-state outputs having high sink- and source-current capability. Two disable controls are provided, one of which controls four buffers and the other controls the remaining two buffers.

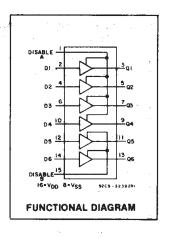
The CD4503B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

Features:

- 1 TTL-load output drive capability
- 2 output-disable controls
- 3-state outputs
- Pin compatible with industry types MM80C97, MC14503, and 340097
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- 3-state hex buffer for interfacing IC's with data buses
- CMOS to TTL hex buffer



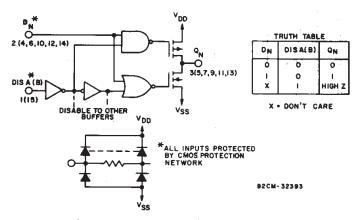


Fig. 1-Logic diagram of 1 to 6 identical buffers.

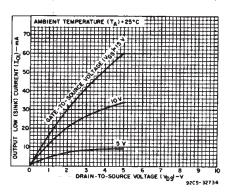


Fig. 2—Typical n-channel output low (sink) current characteristics.

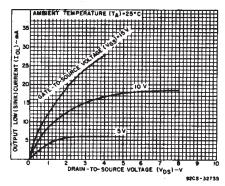
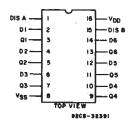


Fig. 3—Minimum n-channel output low (sink) current characteristics.



TERMINAL ASSIGNMENT

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	0.5V to Vnn +0.5V
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C Derate Line	arity at 12mW/OC to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	•
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)	65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max	+265°C

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CD4503B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARAC- TERISTIC	CON	OITIO	NS	LIMITS AT INDICATED TEMPERATURES (°C)					N		
	Vo	VIN	V _{DD}		-				+ 25		Ţ
	(v)	(V)	(٧)	—55	-40	+ 85	+ 125	Min.	Тур.	Max.	S
Quiescent	_	0,5	5	1	1	30	30		0.02	1	
Device		0,10	10	2	2	60	60	_	0.02	2	
Current,	_	0,15	15	4	4	120	120	_	0.02	4	μΑ
IDD Max.	_	0,20	20	20	20	600	600	_	0.04	20	ŀ
Output							-				
Low	0.4	0	5	2.6	2.5	1.4	1.3	2.1	2.3		
(Sink)	0.5	0	10	6.5	6.4	3.9	3.8	5.5	6.2		
Current	1.5	0	15	19.2	18.9	.11.4	11.2	16.1	23	· · ·—	
IOL Min.					<u></u>			l	<u> </u>		
Output	4.6	5	5	—1.2	-1.16	.—0.7	-0.7	-1.02	1.9		m A
High	2.5	5	5	-5.8	-5.7	-3.4	-0.7	-1.02	-6.1	=	11112
(Source)	9.5	10	10	-3.1	-3	-1.9	-1.8	-2.6			
Current,	13.5	15	15	8.2	-8	-4.9	-4.8	-6.8			
IOH Min.					L	7.0	1.50	0.0	— 144. I	. — 	
Output											
Voltage:	_	0,5	5		0.0	05	-	. 0	0.05		
Low-											
Level,		0,10	10	0.05				<u> </u>	0	0.05	
VOL Max.	10 <u>4</u> .	0,15	15		0.0)5			0	0.05	v
Output									*		
Voltage:		0,5	5		4.9	95		4.95	5	-	
High-											
Level,		0,10	10			95		9.95	10	_	
VOH Min.	-	0,15	15		14.		<u> </u>	14.95	15		L
Input Low	0.5,4.5	_	5		1.		<u> </u>	_		1.5	
Voltage,	1,9		10		3		<u> </u>			3	
VIL Max.	1.5,13.5		15		4	·				4	
Input						_ < -	<u> 1</u>		<u> </u>		V
High	0.5,4.5		5	3.5 3.5 —					, ,		
Voltage,	1,9		10	7				7	_ `		
VIH Min.	1.5,13.5		15	11 11							
Input		0.40							اء		
Current	_	0,18	18	± 0.1	± 0.1	±1	±1	_	± 10 ⁻⁵	± 0.1	
IN Max.		_			ļ					\Box	
3-State											μΑ
Output									اما		
Leakage	0,18	0,18	18	± 0.4	± 0.4	± 12	± 12	-	± 10 ⁻⁴	± 0.4	
Current,											,
OUT											7
Max.											



For maximum reliability, nominal operating conditions should be selected that operation is always within the following ranges:

		• •	
CHARACTERISTIC	LIA	UNITO	
CHARACTERISTIC	Min.	Max.	UNITS
Supply-Voltage Range (For			
TA = Full Package- Temperature Range)	3	18	٧

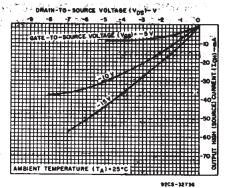


Fig. 4—Typical p-channel output high (source) current characteristics.

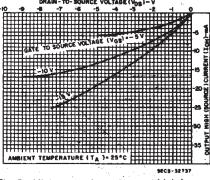


Fig. 5—Minimum p-channel output high (source) current characteristics.

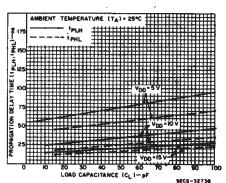


Fig. 6—Typical propagation delay time as a function of load capacitance.

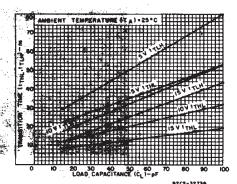


Fig. 7—Typical transition time as a function of load capacitance.

CD4503B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C; Input t_f , t_f = 20 ns, C_L = 50 pF, R_L = 200 k Ω unless otherwise specified.

CHARACTERISTIC	V _{DD}	LIN		
CHARACTERISTIC	(v)	Тур.	Max.	UNITS
Propagation Delay Time:	5	75	150	
Low-to-High, tpLH	10 15	35 25	70 50	ns
High-to-Low, t _{PHL}	5 10 15	55 25 17	110 50 35	ns
Transition Time: Low-to-High, t _{TLH}	5 10 15	50 30 25	90 45 35	ns
High-to-Low, t _{THL}	5 10 15	35 20 13	70 40 25	ns
3-State Propagation Delay Time: R _L = 1 kΩ [†] PHZ, [†] PZH	5 10 15	70 30 25	140 60 50	ns
[†] PZL, [†] PLZ	5 10 15	90 40 35	180 80 70	ns

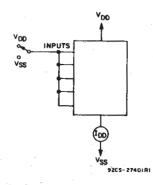


Fig. 10-Quiescent-device-current test circuit.

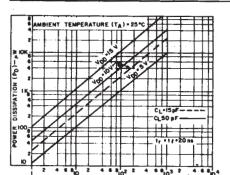


Fig. 8—Typical power dissipation as a function of frequency.

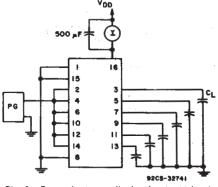


Fig. 9—Dynamic power dissipation test circuit.

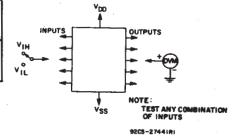


Fig. 11-Input-voltage test circuit.

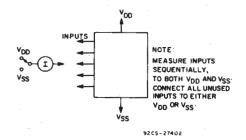
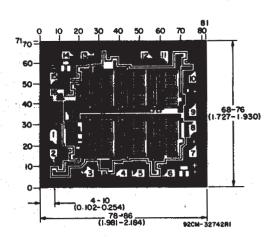


Fig. 12-Input current test circuit.



Dimensions and pad layout for CD4503BH

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch):





ti.com 28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4503BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4503BF	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD4503BF3A	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD4503BM	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4503BM96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4503BMT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4503BNSR	ACTIVE	SO	NS	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4503BPW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD4503BPWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

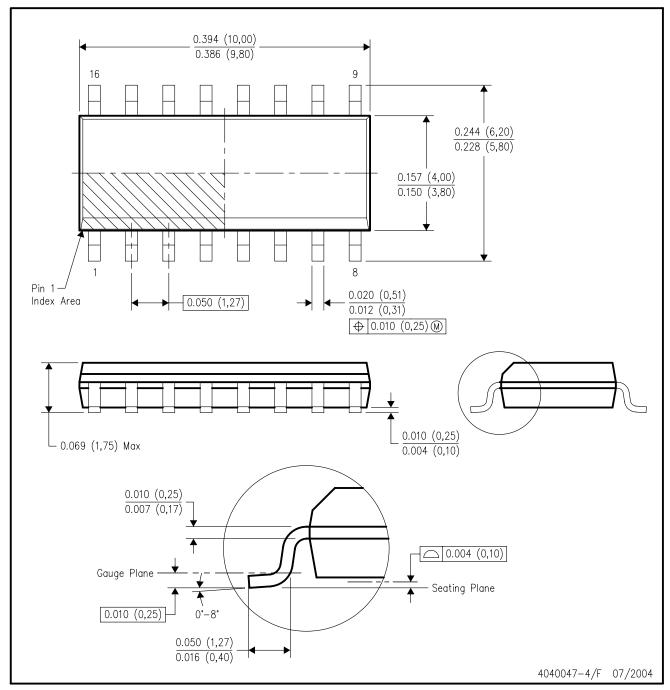


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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